

## KSE13001

### **Color TV Chroma Output**

- Collector-Base Voltage: V<sub>CBO</sub>=400V
   Current Gain Bandwidth Product: f<sub>T</sub>=50MHz (TYP.)



1. Base 2. Collector 3. Emitter

# **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	400	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
I <sub>C</sub>	Collector Current	100	mA
P <sub>C</sub>	Collector Power Dissipation	600	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ +150	°C

### **Electrical Characteristics** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C=100\mu A, I_E=0$	400			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =5mA, I <sub>B</sub> =0	400			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =100μA, I <sub>C</sub> =0	7			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =200V, I <sub>E</sub> =0			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =10V, I <sub>C</sub> =20mA	40		80	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =1mA			0.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =30V, I <sub>C</sub> =10mA		50		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		4		pF

## **h**<sub>FE</sub> Classification

Classification	R	0
h <sub>FE</sub>	40 ~ 65	55 ~ 80

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# **Typical Characteristics**

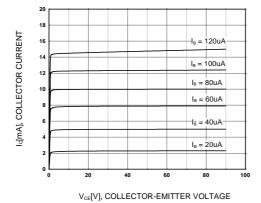
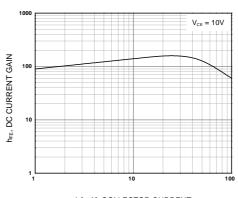


Figure 1. Static Characteristic



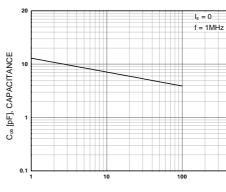
I<sub>c</sub>[mA], COLLECTOR CURRENT

Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage



I<sub>C</sub>[mA], COLLECTOR CURRENT

Figure 2. DC current Gain



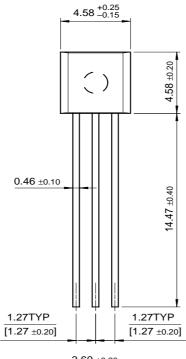
V<sub>CB</sub> [V], COLLECTOR-BASE VOLTAGE

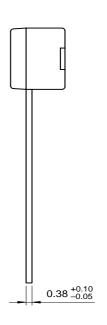
Figure 4. Collector Output Capacitance

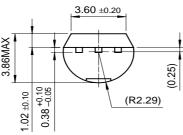
V<sub>BE</sub>(sat), V<sub>CE</sub>(sat)[V], SATURATION VOLTAGE

# **Package Demensions**

# TO-92







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